Programmable Sensor Interface



#### 1. Features and Benefits

- Microprocessor-controlled signal conditioning for bridge-type sensors
- Suited for low-cost sensors: reduction of non-linearity by programmable coefficients
- External or internal temperature sensor for compensating temperature errors
- Versatile output signal ranges: 4, 5, 10, or 11VDC; 4 to 20 mA loop
- Mass calibration easy with 2400 or 9600 baud UART
- Power supply from 6 to 35VDC

#### 2. Application Examples

- Pressure transducers
- Accelerometers
- Temperature sensor assemblies
- Linear position sensors

### 3. Ordering information

Product Code	Temperature Code	Package Code	Option Code	Packing Form Code
MLX90314	L	DF	BBA-000	TU
MLX90314	L	DF	BBA-000	RE

#### Legend:

Temperature Code: L for Temperature Range -40°C to 150°C

Package Code: DF for SOIC300Mil
Packing Form: RE for Reel, TU for Tube
Ordering example: MLX90314LDF-BAA-000-TU



#### 4. Functional Diagram

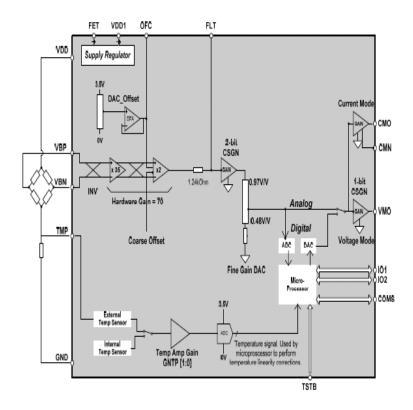


Figure 1. Functional Block Diagram

### 5. General Description

The MLX90314 is a dedicated microcontroller which performs signal conditioning for sensors wired in bridge or differential configurations. Sensors that can be used include thermistors, strain gauges, load cells, pressure sensors, accelerometers, etc. The signal conditioning includes gain adjustment, offset control, high order temperature and linearity compensation. Compensation values are stored in EEPROM and are re-programmable. Programming is accomplished by using a PC, with an interface circuit (level shifting and glue logic), and provided software.

The application circuits can provide an output of an absolute voltage, relative voltage, or current. The output can be range limited with defined outputs when the signal is beyond the programmed limits. Other features include alarm outputs and level steering. The robust electrical design allows the MLX90314 to be used where most signal conditioning and sensor interface circuits cannot be used. Voltage regulation control is provided for absolute voltage and current modes (external FET required).

The standard package is a plastic SO16W. The device is static-sensitive and requires ESD precautions.





### **Contents**

1. Features and Benefits	1
2. Application Examples	1
3. Ordering information	1
4. Functional Diagram	2
5. General Description	2
6. Electrical Specifications	4
7. Unique Features	8
7.1. Customization	8
7.2. Special Information	8
7.3. Programming and Setup	8
7.4. Cross Reference	8
7.5. ESD Precautions	8
8. Pin Description	10
9. Analog Features	11
10. Digital Features	12
11. Different Modes	13
12. Communications	17
13. Typical 90314 Applications	26
14. Standard information regarding manufacturability of Melexis products with different soldering processes	32
15. Contact	33
16. Disclaimer	33





### **6. Electrical Specifications**

DC operating parameters:  $T_A = -40$  to 140°C,  $V_{DD1} = 6$  to  $35V_{DC}$  (unless otherwise specified).

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Regulator & Consumption						
Input voltage range	V <sub>IN</sub>	V <sub>DD1</sub> (Regulator connected)	6		35	V
Supply current	I <sub>DD</sub>	@ T <sub>A</sub> = 100°C Current Mode		2.1		mA
Supply current	I <sub>DD</sub>	@ T <sub>A</sub> = 100°C Voltage Mode			5.0	mA
Regulated supply voltage	$V_{REG}$		4.5	4.75	5.2	V
Regulated voltage temperature coefficient				-600		uV / ºC
Supply rejection ratio	PSRR	V <sub>DD1</sub> > 6V	90			dB
Instrumentation Amplifier				T	ı	·
Differential input range	VBP-VBN	IINV = O	-2.88		8.38	mV/V <sub>(Vdd)</sub>
Differential input range	VBP-VBN	IINV = 1	-8.38		2.88	mV/V <sub>(Vdd)</sub>
Common mode input range		1/2(VBP+VBN)	38.0		65.0	%VDD
Pin leakage current		Pins VBP & VBN to GND, $V_{DD} =$			8.0	nA
Common mode rejection Ratio CMRR			60			dB
Hardware gain			69		84	V/V
Coarse offset control Range	j	CSOF[1:0] = 00	-4.37		-3.97	mV/V
		CSOF[1:0] = 01	-1.46		-1.09	mV/V
		CSOF[1:0] = 10	1.09		1.46	mV/V
		CSOF[1:0] = 11	3.97		4.37	mV/V
Fixed offset control range		High	1.71		2.29	mV/V
		Low	-2.00		-1.43	mV/V
IA chopper frequency	•			300		kHz
Gain Stage						
Course gain		CSGN = 000	3.0		3.3	V/V
(Fixed Gain = 1023)		CSGN = 001	4.9		5.4	V/V
* CSGN = 100 to 111:		CSGN = 010	8.0		8.8	V/V
voltage mode only, not applicable to current mode.		CSGN = 011	12.8		14.1	V/V
Output > 6.5V; MSB = 1		CSGN = 100*	7.9		8.7	V/V
Output < 6.5V; MSB = 0		CSGN = 101*	12.7		14.0	V/V





DC operating parameters:  $T_A = -40$  to  $140^{\circ}$ C,  $V_{DD1} = 6$  to  $35V_{DC}$  (unless otherwise specified).

Coarse gain   CSGN = 110°   20.4   23.0   V/V	Parameter	Test Conditions	Min	Тур	Max	Units
Fixed gain control range   D.480   D.970   V/V	Coarse gain	CSGN = 110*	20.4		23.0	V/V
Digital Mode & Current Mode Coarse Gain Stage		CSGN = 111*	33.1		36.6	V/V
Course Gain         CSGN = 00         1.05         1.17         V/V           CSGN = 01         1.71         1.89         V/V           CSGN = 10         2.77         3.06         V/V           Voltage Mode Output Stage (See Voltage Mode)         V/V         V/V           Output voltage span         CSGN[2:2] = 0         4.5         6.5         V           Gain         2.74         3.04         V/V           CSGN[2:2] = 1         6.5         11         V           Gian         7.24         7.86         V/V           Minimum output voltage         0.2         V           Output source current         2.0         mA           Output sink current         @ 0V output voltage         20         mA           Output resistance         Over complete output range         25         Ohms           Digital mode output span         CSGN[2:2] = 0         6.5         V           Oigt and mode step size         VDD = 5V, CSGN[2:2] = 0         6.5         mV           Digital mode otyput Stage         VDD = 5V, CSGN[2:2] = 1         11.0         mF           Current Mode Output Stage         VDD = 5V, CSGN[2:2] = 1         11.0         mA           Current sense resist	Fixed gain control range		0.480		0.970	V/V
Course Gain         CSGN = 01         1.71         1.89         V/V           CSGN = 10         2.77         3.06         V/V           Voltage Mode Output Stage ( See Voltage Mode)         V         V           Output voltage span         CSGN[2:2] = 0         4.5         6.5         V           Gain         2.74         3.04         V/V           CSGN[2:2] = 1         6.5         11         V           Gain         7.24         7.86         V/V           Minimum output voltage         -0.2         V           Output source current         2.0         mA           Output sink current         @ 0V output voltage         20         uA           Output resistance         Over complete output range         25         Ohms           Digital mode output span         CSGN[2:2] = 0         6.5         V           Digital mode step size         VDD = 5V, CSGN[2:2] = 0         6.5         mV           Output current Mode Output Stage         VDD = 5V, CSGN[2:2] = 1         11.0         mV           Capacitive load VMO pin         To put source tempt source	Digital Mode & Current Mode Coarse Gain S	tage				
Course Gain         CSGN = 10         2.77         3.06         V/V           CSGN = 11         4.48         4.95         V/V           Voltage Mode Output Stage ( See Voltage Mode)         V           Output voltage span         CSGN[2:2] = 0         4.5         6.5         V           Gain         2.74         3.04         V/V           Minimum output voltage         6.5         11         V           Output source current         2.0         mA           Output sink current         @ 0V output voltage         20         uA           Output resistance         Over complete output range         25         Ohms           Digital mode output span         CSGN[2:2] = 0         6.5         V           Digital mode step size         VDD = 5V, CSGN[2:2] = 0         6.5         mV           Digital mode step size         VDD = 5V, CSGN[2:2] = 0         6.5         mV           Capacitive load VMO pin         10         nF         nF           Current Mode Output Stage         24         Ohms           Fixed gain         RSENSE = 24 ohm         8.4         9.3         mA/V           Output current CMO pin         Current mode         27         mA           Current sense		CSGN = 00	1.05		1.17	V/V
CSGN = 10	Causea Calia	CSGN = 01	1.71		1.89	V/V
Output voltage span   CSGN[2:2] = 0	Course Gain	CSGN = 10	2.77		3.06	V/V
Output voltage span         CSGN[2:2] = 0         4.5         6.5         V           Gain         2.74         3.04         V/V           CSGN[2:2] = 1         6.5         11         V           Gain         7.24         7.86         V/V           Minimum output voltage         -0.2         V           Output source current         2.0         mA           Output sink current         @ 0V output voltage         20         uA           Output resistance         Over complete output range         25         Ohms           Digital mode output span         CSGN[2:2] = 0         6.5         V           CSGN[2:2] = 1         11.0         V           Digital mode step size         VDD = 5V, CSGN[2:2]=0         6.5         mV           VDD = 5V, CSGN[2:2]=1         11.0         mV           Capacitive load VMO pin         10         nF           Current Mode Output Stage           Fixed gain         RSENSE = 24 ohm         8.4         9.3         mA/V           Output current CMO pin         Current mode         27         mA           Current sense resistor         24         Ohms           Digital mode current output span         VDD = 5V, RSENSE=24Ω		CSGN = 11	4.48		4.95	V/V
Gain   2.74   3.04   V/V	Voltage Mode Output Stage (See	Voltage Mode)				
CSGN[2:2] = 1	Output voltage span	CSGN[2:2] = 0	4.5		6.5	V
Gain   7.24   7.86   V/V		Gain	2.74		3.04	V/V
Minimum output voltage		CSGN[2:2] = 1	6.5		11	٧
Output source current         2.0         mA           Output sink current         @ 0V output voltage         20         uA           Output resistance         Over complete output range         25         Ohms           Digital mode output span         CSGN[2:2] = 0         6.5         V           Digital mode step size         VDD = 5V, CSGN[2:2]=0         6.5         mV           VDD = 5V, CSGN[2:2]=1         11.0         mV           Capacitive load VMO pin         10         nF           Current Mode Output Stage           Fixed gain         RSENSE = 24 ohm         8.4         9.3         mA/V           Output current CMO pin         Current mode         27         mA           Current sense resistor         24         Ohms           Digital mode current output span         VDD = 5V, RSENSE=24Ω         30         uA           Signal Path (General)         Voltage mode         98         2100         V/V           Overall gain         Voltage mode         98         2100         V/V           Overall non-linearity         -0.25         0.25         %           Ratiometry Error (4.75V – 5.25V)         Overall Gain < 250V/V		Gain	7.24		7.86	V/V
Output sink current         @ 0V output voltage         20         uA           Output resistance         Over complete output range         25         Ohms           Digital mode output span         CSGN[2:2] = 0         6.5         V           Digital mode step size         VDD = 5V, CSGN[2:2]=0         6.5         mV           Digital mode step size         VDD = 5V, CSGN[2:2]=1         11.0         mV           Capacitive load VMO pin         10         nF           Current Mode Output Stage           Fixed gain         RSENSE = 24 ohm         8.4         9.3         mA/V           Output current CMO pin         Current mode         27         mA           Current sense resistor         24         Ohms           Digital mode current output span         VDD = 5V         23         mA           Digital mode current step Size         VDD = 5V,RSENSE=24Ω         30         uA           Signal Path ( General)         Voltage mode         98         2100         V/V           Overall gain         Voltage mode         98         2100         V/V           Overall non-linearity         -0.25         0.25         %           Ratiometry Error (4.75V – 5.25V)         Overall Gain < 250V/V	Minimum output voltage	1			-0.2	٧
Output resistance         Over complete output range         25         Ohms           Digital mode output span         CSGN[2:2] = 0         6.5         V           Digital mode step size         VDD = 5V, CSGN[2:2]=0         6.5         mV           Digital mode step size         VDD = 5V, CSGN[2:2]=0         6.5         mV           Capacitive load VMO pin         10         nF           Current Mode Output Stage           Fixed gain         RSENSE = 24 ohm         8.4         9.3         mA/V           Output current CMO pin         Current mode         27         mA           Current sense resistor         24         Ohms           Digital mode current output span         VDD = 5V         23         mA           Digital mode current step Size         VDD = 5V,RSENSE=24Ω         30         uA           Signal Path ( General)           Overall gain         Voltage mode         98         2100         V/V           Overall non-linearity         -0.25         0.25         %           Ratiometry Error (4.75V – 5.25V)         Overall Gain < 250V/V	Output source current		2.0			mA
	Output sink current	@ 0V output voltage	20			uA
Digital mode output span   CSGN[2:2] = 1   11.0   V	Output resistance	Over complete output range			25	Ohms
CSGN[2:2] = 1	Digital made output span	CSGN[2:2] = 0	6.5			V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Digital mode output span	CSGN[2:2] = 1	11.0			V
Capacitive load VMO pin 10 nF  Current Mode Output Stage  Fixed gain RSENSE = 24 ohm 8.4 9.3 mA/V  Output current CMO pin Current mode 27 mA  Current sense resistor 24 Ohms  Digital mode current output span VDD = 5V 23 mA  Digital mode current step Size VDD = 5V,RSENSE=24 $\Omega$ 30 uA  Signal Path (General)  Overall gain Voltage mode 98 2100 V/V  Current mode = 24 $\Omega$ 284 2625 mA/V  Overall non-linearity -0.25 0.25 %  Ratiometry Error (4.75V - 5.25V) Overall Gain < 250V/V -1.75 1.75 %	Digital made stansize	VDD = 5V, CSGN[2:2]=0		6.5		mV
Current Mode Output StageFixed gainRSENSE = 24 ohm8.49.3mA/VOutput current CMO pinCurrent mode27mACurrent sense resistor24OhmsDigital mode current output spanVDD = 5V23mADigital mode current step SizeVDD = 5V,RSENSE=24 $\Omega$ 30uASignal Path (General)Overall gainVoltage mode982100V/VCurrent mode = 24 $\Omega$ 2842625mA/VOverall non-linearity-0.250.25%Ratiometry Error (4.75V - 5.25V)Overall Gain < 250V/V	Digital mode step size	VDD = 5V, CSGN[2:2]=1		11.0		mV
Fixed gain RSENSE = 24 ohm 8.4 9.3 mA/V Output current CMO pin Current mode 27 mA Current sense resistor 24 Ohms Digital mode current output span VDD = 5V 23 mA Digital mode current step Size VDD = 5V,RSENSE=24 $\Omega$ 30 uA Signal Path (General) Voltage mode 98 2100 V/V Current mode = 24 $\Omega$ 284 2625 mA/V Overall non-linearity -0.25 0.25 % Ratiometry Error (4.75V – 5.25V) Overall Gain < 250V/V -1.75 1.75 %	Capacitive load VMO pin			10		nF
Output current CMO pinCurrent mode27mACurrent sense resistor24OhmsDigital mode current output spanVDD = 5V23mADigital mode current step SizeVDD = 5V,RSENSE=24 $\Omega$ 30uASignal Path (General)Overall gainVoltage mode982100V/VCurrent mode = 24 $\Omega$ 2842625mA/VOverall non-linearity-0.250.25%Ratiometry Error (4.75V - 5.25V)Overall Gain < 250V/V	Current Mode Output Stage					
Current sense resistor24OhmsDigital mode current output spanVDD = 5V23mADigital mode current step SizeVDD = 5V,RSENSE=24 $\Omega$ 30uASignal Path (General)Overall gainVoltage mode982100V/VCurrent mode = 24 $\Omega$ 2842625mA/VOverall non-linearity-0.250.25%Ratiometry Error (4.75V - 5.25V)Overall Gain < 250V/V	Fixed gain	RSENSE = 24 ohm	8.4		9.3	mA/V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Output current CMO pin	Current mode		27		mA
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Current sense resistor			24		Ohms
	Digital mode current output span	VDD = 5V	23			mA
Overall gain       Voltage mode       98       2100       V/V         Current mode = $24\Omega$ 284       2625       mA/V         Overall non-linearity       -0.25       0.25       %         Ratiometry Error (4.75V – 5.25V)       Overall Gain < 250V/V	Digital mode current step Size	VDD = 5V,RSENSE=24Ω		30		uA
Overall gain         Current mode = $24\Omega$ 284       2625       mA/V         Overall non-linearity       -0.25       0.25       %         Ratiometry Error (4.75V – 5.25V)       Overall Gain < 250V/V	Signal Path ( General)					
Current mode = 24Ω       284       2625       mA/V         Overall non-linearity       -0.25       0.25       %         Ratiometry Error (4.75V – 5.25V)       Overall Gain < 250V/V	Ovorall gain	Voltage mode	98		2100	V/V
Ratiometry Error (4.75V – 5.25V)	Overall galli	Current mode = $24\Omega$	284		2625	mA/V
	Overall non-linearity		-0.25		0.25	%
Overall Gain > 250V/V -4.6 +4.6 %	Ratiometry Error (4.75V – 5.25V)	Overall Gain < 250V/V	-1.75		1.75	%
		Overall Gain > 250V/V	-4.6		+4.6	%



Programmable Sensor Interface

DC operating parameters:  $T_A = -40$  to  $140^{\circ}$ C,  $V_{DD1} = 6$  to  $35V_{DC}$  (unless otherwise specified).

Parameter	Test conditions	Min	Тур	Max	Units
Bandwidth (-3dB)	39 nF connected from FLT to GND	2.8	3.5	4.2	KHz
Noise, VDD = 5V, CFLT=39nF, CL=10nF, RL =5KΩ, An	nalog Mode (Max. gain)			17	mVRMS
Temperature Sensor & - Amplifier			390		14/00
Temperature sensor sensitivity			590	222	uV/ºC
Temperature sensor output voltage		70		380	mV
Temperature Sensor & Amplifier (cor	itinued).				
Input voltage range TMP pin	GNTP[1,0] = 00	207		517	mV
@ V <sub>DD</sub> = 5.0V	GNTP[1,0] = 01	145		367	mV
	GNTP[1,0] = 10	101		263	mV
	GNTP[1,0] = 11	71		186	mV
DAC					
Resolution			10		Bit
Monotonicity		Guaranteed By Design			
Ratiometric output range (DAC output)		1		75	% V <sub>DD</sub>
Offset Error			10		LSB
Differential non-linearly				1	LSB
Integral non-linearity				2	LSB
ADC					
Resolution			10		Bit
Monotonicity	Monotonicity		Guaranteed by design		
Ratiometric input range		1		75	% V <sub>DD</sub>
Offset error			10		LSB
Differential non-linearly				1	LSB
Integral non-linearity				2	LSB
On-Chip RC Oscillator and Clock					
Untrimmed RC		40		250	kHz
oscillator frequency					
Trimmed RC oscillator frequency (Measured at TMP pin with TSTB pin pulled low after power up)		86.9	87.8	88.7	kHz
Frequency temperature coefficiency			26		Hz/ºC
Clock Stability with temperature compensation over full temperature		-3		+3	%
range	,				
Ratio of f (microcontroller main	TURBO = 0		7		
clock and (RC oscillator)	TURBO = 1		28		





DC operating parameters:  $T_A = -40$  to  $140^{\circ}$ C,  $V_{DD1} = 6$  to  $35V_{DC}$  (unless otherwise specified).

Parameter	Test Conditions	Min	Тур	Max	Units
Input & Output Pins (I01 & I02	)				
Digital input levels	Low High	0.5		V <sub>DD</sub> -0.5	V
Output Levels	@ output current = 5mA low @ Output current = 5mA high	V <sub>DD</sub> -0.4	V <sub>DD</sub>	0.4	V
STB Pin	С самрае самено сим нада				
Input levels	Low High	0.5		V <sub>DD</sub> -0.5	V
Pull-up Resistor	L		66		kOhms
FLT Pin					
Output resistance			1.24		kOhms
Output voltage range	VDD = 5V	0.05		3.6	V
OFC Pin					
Output voltage range	VDD = 5V	0.05		3.75	V
Load capacitor				20	Pf
UART & COMS Pin					
UART baud rate	TURBO = 0		2400		baud
	TURBO = 1		9600		baud
COMS pin input levels	Low	0.3*V <sub>DD</sub>			V
	High			0.7*V <sub>DD</sub>	V
COMS Pin Output Resistance	Low		100		Ohms
	High		100		kOhms

Programmable Sensor Interface



#### 7. Unique Features

#### 7.1. Customization

Melexis can customize the MLX90314 in both hardware and firmware for unique requirements. The hardware design provides 64 bytes of RAM, 3 kbytes of ROM, and 48 bytes of EEPROM for use by the firmware.

#### 7.2. Special Information

The output of the sensor bridge is amplified via offset and gain amplifiers and then converted to the correct output signal form in one of the output stages.

The sensitivity and offset of the analog signal chain are defined by numbers passed to the DAC interfaces from the microcontroller core (GN[9:0] and OF[9:0]). The wide range of bridge offset and gain is accommodated by means of a 2-bit coarse adjustment DAC in the offset adjustment (CSOF[1:0]), and a similar one in the gain adjustment (CSGN[2:0]). The signal path can be directed through the processor for digital processing. Two I/O pins are available for analog inputs or digital outputs. These pins can be used for alarms on various points on the analog signal path and built-in or external temperature values.

#### 7.3. Programming and Setup

The MLX90314 needs to have the compensation coefficients programmed for a particular bridge sensor to create the sensor system. Programming the EEPROM involves some minimal communications interface circuitry, Melexis' setup software, and a PC. The communications interface circuitry is available in a development board. This circuitry communicates with the PC via a standard RS-232 serial communications port.

#### 7.4. Cross Reference

There are no known devices which the MLX90314 can replace.

#### 7.5. ESD Precautions

Observe standard ESD control procedures for CMOS semiconductors.

#### Programmable Sensor Interface



#### Table 2. Absolute Maximum Ratings

Supply voltage (ratiometric) VDD	6V
Supply voltage (ratiometric) VDD	4.5V
Supply voltage (operating), VDD1	35V
Reverse voltage protection	-0.7V
Supply current, Current Mode, IDD	3.5mA
Supply current, Voltage Mode, IDD	4.5mA
Output current, IVMO	8mA
Output current (short to V <sub>DD</sub> ),	100mA
Output current (short to VSS),	8mA
Output voltage, VVMO	+11V
Power dissipation, PD	71mW
Operating temperature range, TA	-40 to +140°
Storage temperature range, TS	-55 to +150°
Maximum junction temperature, TJ	150℃



### 8. Pin Description

Table 3 Pin Description

Pin	Signal	Description
1,2	Name I/O1, 2	Bi-directional I/O. Can also be used as input to A/D converter. I/O can be controlled by serial communications or by firmware as alarm inputs or level out. (unconnected when not used)
3	TSTB	Test pin for Melexis production testing. (in normal application connected to VDD)
4	FLT	Filter pin; allows for connection of a capacitor to the internal analog path.
5	OFC	Offset control output. Provides access to the internal programmed offset control voltage for use with external circuitry. (unconnected when not used)
6,7	VBN,VBP	Bridge inputs, negative and positive.
8	TMP	Temperature sensor input. An external temperature sensor can be used in conjunction with the internal one. The external sensor can provide a temperature reading at the location of the bridge sensor.
9	V <sub>DD</sub>	Regulated supply voltage. Used for internal analog circuitry to ensure accurate and stable signal manipulation.
10	FET	Regulator FET gate control. For generating a stable supply for the bridge sensor and internal analog circuitry (generates regulated voltage for VDD).
11	$V_{DD1}$	Unregulated supply voltage. Used for digital circuitry and to generate FET output.
12	VMO	Voltage mode output. Compensated sensor output voltage.
13	СМО	Current mode output. Compensated sensor output for current mode operation.
14	CMN	Current mode negative rail. Current mode return path.
15	GND	Power supply return.
16	COMS	Serial communications pin. Bi-directional serial communication signal for reading and writing to the EEPROM.

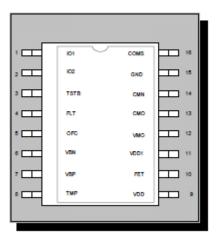


Figure 2. Pinout (SO16W (LW) Package)

Programmable Sensor Interface



#### 9. Analog Features

#### **Supply Regulator**

A bandgap-stabilized supply-regulator is on-chip while the pass-transistor is external. The bridge-type sensor is typically powered by the regulated supply (typically

4.75V). For ratiometric operation, the supplyregulator can be disabled by connecting together the unregulated and regulated supply pins.

#### Oscillator

The MLX90314 contains a programmable on-chip RC oscillator. No external components are needed to set the frequency (87.8 kHz +/-1%). The MCU-clock is generated by a PLL (phase locked loop tuned for 614 kHz or 2.46 Mhz) which locks on the basic oscillator.

The frequency of the internal clock is stabilized over the full temperature range, which is divided into three regions, each region having a separate digital clock setting. All of the clock frequency programming is done by Melexis during final test of the component. The device uses the internal temperature sensor to determine which temperature range setting to use.

#### A/D and D/A

#### Conversions using only one DAC

For saving chip area, the "Offset DAC" is multiplexed in various ways. Both "fine offset" and "digital mode" signals are stored on a capacitor. An ADC-loop is available by using a comparator and SAR.

#### D/A

Before changing to another capacitor, the DAC output should be settled to the new value. For example, MODSEL moves the analog multiplexer to the so- called "open state 0." At the same time, the 10 bit mux selects OF[9:0] for the offset-DAC. After the DAC settling time, the analog multiplexer is moved to its final state and the DAC-output is stored on a capacitor.

#### A/D

The S/W-Signal MODSEL connects the SAR-output to the DAC and the DAC-output to the comparator. The SARegister is initialized by a rising edge of STC (S/W signal). At the end of the A/D conversion, the EOC flag is set to 1 and the controller can read the ADC values.

#### **Power-On Reset**

The Power-On Reset (POR) initializes the state of the digital part after power up. The reset circuitry is completely internal. The chip is completely reset and fully operational 3.5 ms from the time the supply crosses

3.5 volts. The POR circuitry will issue another POR if the supply voltage goes below this threshold for 1.0 us.

#### **Test Mode**

For 100% testability, a "TEST" pin is provided. If the pin is pulled low, then the monitor program is entered and the chip changes its functionality. In all other applications, this pin should be pulled high or left floating (internal pull-up).

#### **Temperature Sense**

The temperature measurement, TPO, is generated from the external or internal temperature sensor. This is converted to a 10-bit number for use in calculating the signal compensation factors. A 2-bit coarse adjustment GNTP[1:0] is used for the temperature signal gain & offset adjustment.

Programmable Sensor Interface



#### **10.** Digital Features

## Microprocessor, LX11 Core, Interrupt Controller, Memories

The LX11 microcontroller core is described in its own datasheet. As an overview, this implementation of the LX11 RISC core has following resources:

Two accumulators, one index and two interrupt accumulators.

15 - 8 bit I/O ports to internal resources. 64 byte RAM.

4 kbytes ROM: 3 kbytes is available for the customer's application firmware. 1k is reserved for test.

48 x 8 bit EEPROM.

Four interrupt sources, two UART interrupts and two timers.

#### **UART**

The serial link is a potentially full-duplex UART. It is receive-buffered, in that it can receive a second byte before a previously received byte has been read from the receiving register. However, if the first byte is not read by the time the reception of the second byte is completed, the first byte will be lost. The UART's baud rate depends on the RC-oscillator's frequency and the "TURBO"-bit (see output port). Transmitted and received data has the following structure: start bit = 0, 8 bits of data, stop bit = 1.

#### **Sending Data**

Writing a byte to port 1 automatically starts a transmission sequence. The TX Interrupt is set when the STOP-bit of the byte is latched on the serial line.

#### **Receiving Data**

Reception is initialized by a 1 to 0 transition on the serial line (i.e., a START-bit). The baud rate period (i.e., the duration of one bit) is divided into 16 phases. The first six and last seven phases of a bit are not used. The decision on the bit-value is then the result of a majority vote of phase 7, 8 and 9 (i.e., the center of the bit).

Spike synchronization is avoided by de-bouncing on the incoming data and a verification of the START-bit value. The RX Interrupt is set when the stop bit is latched in the UART.

#### **Timer**

The clock of the timers TMI and TPI is taken directly from the main oscillator. The timers are never reloaded, so the next interrupt will take place 2x oscillator pulses after the first interrupt.

#### **Watch Dog**

An internal watch dog will reset the whole circuit in case of a software crash. If the watch dog counter is not reset at least once every 26 milliseconds (@ 2.46 MHz main clock), the microcontroller and all the peripherals will be reset.

#### **Firmware**

The MLX90314 firmware performs the signal conditioning by either of two means: analog or digital. The analog signal conditioning allows separate offset and gain temperature coefficients for up to four temperature ranges. Digital mode allows for all of the analog capabilities plus up to five different gain values based on the input signal level. Also available in both modes is the capability of range limiting and level steering.

#### **Temperature Processing**

In both analog and digital modes, the temperature reading controls the temperature compensation. This temperature reading is filtered as designated by the user. The filter adjusts the temperature reading by factoring in a portion of the previous value. This helps to minimize the effect of noise when using an external temperature sensor. The filter equation is:

If measured\_temp > Temp\_f(n) then

Temp\_f(n+1) = Temp\_f(n) + [measured\_temp - Temp\_f(n)] /  $[2^{n_factor}]$ .

If measured\_temp < Temp\_f(n),
then</pre>

 $\label{eq:temp_f(n+1) = Temp_f(n) - [measured\_temp - Temp_f(n)] [2 $^{n_factor}$].}$ 

Temp\_f(n+1) = new filtered temperature value. Temp\_f(n) = previous filtered temperature value. Measured\_temp = Value from temperature A to D. N\_factor = Filter value set by the user (four LSB's of byte 25 of EEPROM), range 0-6.

The filtered temperature value, Temp\_f, is stored in RAM bytes 58 and 59. The data is a 10 bit value, left justified in a 16 bit field.

Programmable Sensor Interface

# Melexis INSPIRED ENGINEERING

#### 11. Different Modes

#### **Analog Mode**

The parameters OF and GN represent, respectively, offset correction and span control, while OFTCi and GNTCi represent their temperature coefficients (thermal zero shift and thermal span shift). After reset, the firmware continuously calculates the offset and gain DAC settings as follows: The EEPROM holds parameters GN, OF, OFTCi and GNTCi, where "i" is the gap number and can be  $1 \leq i \leq 4$ . The transfer function is described below.

Vout = FG \* DAC\_GAIN \* CSGN[2:0]

{Vin+DAC OFFSET+CSOF}

lout = FG \* DAC\_GAIN \* CSGN[1:0] \*
{Vin+DAC\_OFFSET+CSOF} \* 8.85mA/V

**FG** = Hardware Gain (~72V/V). Part of the hardware design, and not changeable.

**CSGN** = Course Gain, part of byte 2 in EEPROM.

**CSOF** = Coarse Offset, part of byte 2 in EEPROM.

#### **GAIN**

DAC\_GAIN (new value) ~ GN[9:0] + [GNTCi \* dT]

**GN[9:0]** = Fixed Gain, bytes 3 and 17 in EEPROM. **GNTCi** = Gain TC for a given temperature segment I. GNTCiL and GNTCiH in EEPROM table.

dT = Temp. change within the appropriate gap. How

to calculate gain in the first temp. gap?: DAC\_GAIN

= GN[9:0] - GNTC1 \* (T1 - Temp\_f1) How to

calculate gain in the other temp. gaps?:

2nd gap: DAC\_GAIN = GN[9:0] + GNTC2 \* (Temp\_f2 - T1)

3th gap: DAC\_GAIN = DAC\_GAIN2 + GNTC3 \*

(Temp f3 - T2)

4th gap: DAC\_GAIN = DAC\_GAIN3 + GNTC4 \*

 $(Temp_f4 - T3)$ 

Where:

**Temp\_f** = Filtered temp. (previously described).

If GNTC1 > 2047 => DAC\_GAIN If GNTC2,3,4 > 2047 => DAC\_GAIN

#### **OFFSET**

DAC\_OFFSET (new value) ~ OF[9:0]+[OFTCi\* dT]

**OFTCI** = Fixed Gain, bytes 4 and 17 in EEPROM. **OFTCI** = Offset for a given temperature segment I. OFTCIL and OFTCIH in EEPROM table.

**dT** = Temp. change within the appropriate gap.

Calculation of the offset for a given temperature segment is performed the same way as for the gain.

$$(1.83--1.57)*\frac{OF[9:0]}{1023}-1.57=DAC\_OFFSET^{[mV/V]}$$

[m]

[V/V]

$$(0.97 - 0.48)*\frac{GN[9:0]}{1023} + 0.48 = DAC\_GAIN$$

#### **Digital Mode**

The MLX90314 firmware provides the capability of digitally processing the sensor signal in addition to the analog processing. This capability allows for signal correction.

#### **Signal Correction**

While in digital mode the firmware can perform signal correction. This is an adjustment to the output level based on the input signal level. Adjustment coefficients can be set for five different signal ranges. The output is obtained by the following formula:

Output = (Signal – Pi) \* Pci + Poff where Signal = input signal measurement; Poff = Pressure ordinate

Pi = Pressure signal point (I = 2,3,4,5) Pci = programmed coefficient.

The PCi coefficients are coded on 12 bits: one bit for the sign, one for the unity, and the rest for the decimals. The Pi are coded on 10 bits (0-3FFh) in high-low order.

PNB\_TNB: contains the number of signal points, coded on the four MSB's. The four LSB's are reserved for the number of temperature points. See Table 4 and Table 5.

Programmable Sensor Interface



#### **Compensation Trade-Offs**

A compromise must be made between temperature compensation and pressure correction. The EEPROM space where the signal coefficients are stored is shared with the temperature coefficients, with the result that an EEPROM byte can be used either for a temperature coefficient or for a signal coefficient, but not both. Table 6 presents the possibilities among the maximum number of temperature gaps and the maximum number of signal gaps

Table 4. PNB\_TNB Bit Definition;
Pressure Gaps

# of Drossura Cans	4MSB of PNB_TNB Value
# of Pressure Gaps	
Fixed	15 (F hex)
1	14 (E hex)
2	12 (C hex)
3	10 (A hex)
4	8
5	6

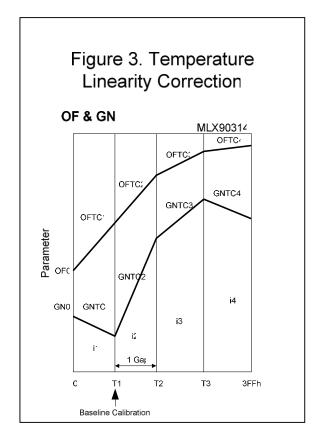
Table 6. Temperature & Signal Limitations

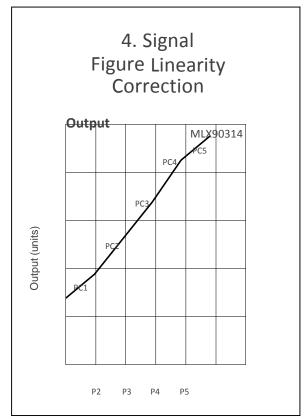
Maximum number of temperature gaps	Maximum number of signal gaps
Fixed Gain and fixed Offset	5 Gaps
2 Gaps	3 Gaps
3 Gaps	2 Gaps
4 Gaps	Fixed signal

Table 5. PNB\_TNB Bit Definition;
Temperature Gaps

# of Temperature Gaps	4 LSB of PNB_TNB
Fixed (1)	0
2 Gaps	5
3 Gaps	8
4 Gaps	11 (B hex)







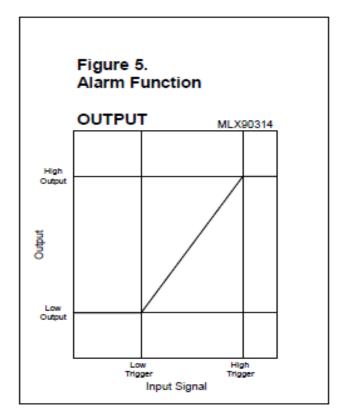


#### Alarm Option

This option allows controlling the low and high limits of the output (See Figure 5.). The output level is set when the output tries to exceed the programmed limits. Five bytes are reserved for this option. The first byte is the low trigger limit and the second the low output. The third and fourth bytes are used for the high limit and the output. The fifth byte is the alarm control, used to select the alarm input. The different levels are programmed as eight bit numbers. These correspond to the 8 upper bits of the 10 bit signal measurement. When the alarm mode is not used, all of the data is 0. The control code is coded as shown in Table 7. The six possible signals are listed below and are encoded on the 4 MSB's of byte 31 of the EEPROM.

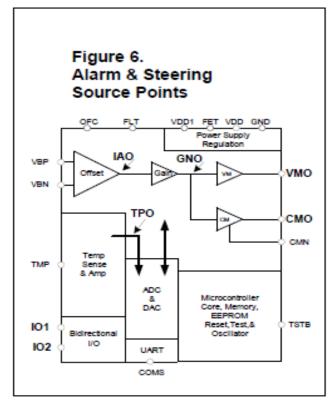
Table 7. Alarm Source Bit Definition

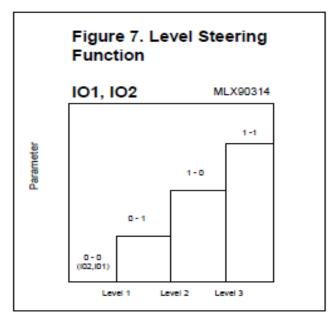
Selected input	MUX Value
TPO	0010
IAO	0110
GNO	0000
VMO	0011
IO1	0100
102	0101



#### IO1 & IO2

IO1 and IO2 are used in the alarm and level steering modes. For custom firmware, they can be used for a digital input, an analog input, or a digital output.







#### **Level Steering**

The level steering option allows configuration of the IO pins as outputs to indicate the relative level of a selected signal. See Figure 7. The levels at which the two outputs change state are programmed by the user. The programmed levels are set as eight bit numbers and compared to the upper eight bits of the digitized signal. This function utilizes the same resources as the alarm function. The two functions (level steering and alarm) cannot be used simultaneously. Four bytes in the EEPROM command this option. The first byte is used to select the input, while the last three comprise the transition levels. The control byte for the level steering is the same as for the alarm. The four MSB's hold the code for the selected input. The control byte has several possibilities as designated by the MUX settings (See Table 8)

### Table 9. Mode Byte Bit Definition

#### 12. Communications

The MLX90314 firmware transfers a complete byte of

data into and from the memory based on a simple command structure. The commands allow data to be read and written to and from the EEPROM and read from the RAM. RAM data that can be read includes the current digitized temperature and digitized GNO. The commands are described below. Melexis provides setup software for programming the MLX90314.

**Table 8. Level Steering Bit Definitions** 

Selected input	MUX Value
TPO	0010
IAO	0110
GNO	0000
VMO	0011

Bit	Function	Remarks
7	1= EEPROM Checksum test active 0= EEPROM Checksum test inactive	EEPROM Checksum test. Checksum test failure will force the output to the value programmed in bytes 40 and 41 of the EEPROM (See Table 10).
6	0 = Analog Mode 1 = Digital Mode	Digital mode must be activated when VMO and CMO both active.
5	0 = Alarm function inactive 1 = Alarm function active	Alarm functions are like "limiting functions":  If defined ADC INPUT is below low alarm trigger, then DIGMOD becomes active with alarm low output).  If defined ADC INPUT is above high alarm trigger, then DIGMOD becomes active with alarm high output.  Note: Deactivated if the level steering mode is active
4	0 = IO1/IO2 are not active outputs 1 = level steering: IO1/IO2 are active outputs	Depending on the sampled input, IO1/IO2 will be a two bit digital output. If IO1/IO2 are not active outputs, then they will be analog inputs.
3	0 = Turbo inactive 1 = Turbo active	
2	0 = VMO inactive 1 = VMO active	
1	0 = Internal temperature sensor active 1 = External temperature sensor active	
0	0 = CMO inactive 1 = CMO active	CMO has fixed digital value (EEPROM byte - see below) if both VMO and CMO are active. To activate this value, the digital mode must be activated.

Programmable Sensor Interface



#### **UART Commands**

The commands can be divided into three parts: (1) downloading of data from the ASIC, (2) uploading of data to the ASIC and (3) the reset command.

All the commands have the same identification bits. The two MSB's of the sent byte indicate the command while the last six MSB's designate the desired address. The commands are coded as followed:

11 to read a RAM byte.
10 to read an EEPROM byte.
01 to write in the EEPROM.
00 to write in the

The addresses can include 0-63 for the RAM, 0-47 for the EEPROM, and 63 for the EEPROM, RESET Command (read).

#### **Downloading Command**

With one byte, data can be downloaded from the ASIC. The ASIC will automatically send the value of the desired byte.

#### **Uploading Command**

Writing to the RAM or EEPROM involves a simple handshaking protocol in which each transmitted is acknowledged by the firmware. The first byte transmitted to the firmware includes both command and address. The firmware acknowledges receipt of the command and address byte by echoing the same information back to the transmitter. This "echo" also indicates that the firmware is ready to receive the byte of data to be stored in RAM or EEPROM. Next, the byte of value to be stored is transmitted and, if successfully received and stored by the firmware, is acknowledged by a "data received signal," which is two bytes of value BCh. If the "data received signal" is not observed, it may be assumed that no value has been stored in RAM or EEPROM.

#### **Reset Command**

Reading the address 63 of the EEPROM resets the ASIC and generates a received receipt indication. Immediately before reset, the ASIC sends a value of BCh to the UART, indicating that the reset has been received.

#### **EEPROM Data**

All user-settable variables are stored in the EEPROM within the MLX90314. The EEPROM is always reprogrammable. Changes to data in the EEPROM do not take effect until the device is reset via a soft reset or power cycle. 12 bit variables are stored on 1.5 bytes. The 4 MSB's are stored in a separate byte and shared with the four MSB's of another 12-bit variable.

#### **Clock Temperature Stabilization**

To provide a stable clock frequency from the internal clock over the entire operating temperature range, three separate clock adjust values are used. Shifts in operating frequency over temperature do not effect the performance but do, however, cause the communications baud rate to change.

The firmware monitors the internal temperature sensor to determine which of three temperature ranges the device currently is in. Each temperature range has a factory set clock adjust value, ClkTC1, ClkTC2, and ClkTC3. The temperature ranges are also factory set. The Ctemp1 and Ctemp2 values differentiate the three ranges. In order for the temperature A to D value to be scaled consistently with what was used during factory programming, the CLKgntp (temperature amplifier gain) valued is stored. The Cadj value stored in byte 1 of the EEPROM is used to control the internal clock frequency while the chip boots.

#### **Unused Bytes**

There are eight unused bytes in the EEPROM address map. These bytes can be used by the user to store information such as a serial number, assembly date code, production line, etc. Melexis doesn't guarantee that these bytes will be available to the user in future revisions of the firmware.

#### **EEPROM Checksum**

A checksum test is used to ensure the contents of the EEPROM. The eight bit sum of all of the EEPROM addresses should have a remainder of 0FFh when the checksum test is enabled (mode byte). Byte 47 is used to make the sum remainder totals 0FFh. If the checksum test fails, the output will be driven to a user defined value, Faultval. When the checksum test is enabled, the checksum is verified at initialization of RAM after a reset.

#### **RAM Data**

All the coefficients (pressure, temperature) are compacted in a manner similar to that used for the EEPROM. They are stored on 12 bits (instead of keeping 16 bits for each coefficient). All the measurements are stored on 16 bits. The user must have access to the RAM and the EEPROM, while interrupt reading of the serial port. Therefore, bytes must be kept available for the return address, the A-accu and the B-accu, when an interrupt occurs. The RAM keeps the same structure in the both modes.



**Table 10. Examples of Fixed Point Signed Numbers** 

Decimal Value	Hexadecimal Equivalent	Fixed Point Signed Number Equivalent
0	0000h	+0.00
1023	3FFh	+0.9990234
1024	400h	+1.000
2047	7FFh	+1.9990234
2048	800h	-0.000
3071	0BFFh	-0.9990234
3072	0C00h	-1.000
4095	0FFFh	-1.9990234

#### **Data Range**

Various data are arranged as follows:

Temperature points: 10 bits, 0-03FF in highlow order.

Pressure points: 10 bits, 0-03FF in high-low order.

GN1: 10 bits, 0-03FF in high-low order. OF1: 10 bits, 0-03FF in high-low order. GNTCi: signed 12 bits (with MSB for the sign), [-1.9990234, +1.9990234].

OFTCi: signed 12 bits (with MSB for the sign), [-1.9990234, +1.9990234].

Pci: signed 12 bits (with MSB for the sign), [-1.9990234, +1.9990234]

DIGMO: 10 bits, 0-03FF in high-low order (See Table 13 for examples of fixed point signed numbers.)

**Table 11. EEPROM Byte Definitions** 

Byte	Designation	Note
0	MODE byte	Contents described in Table 9.
1	Cadj	Controls system clock during boot.
2	Coarse Control	Contents described in Table 12.
3	GN1L	The eight LSB's of the Fixed Gain, GN[7:0].
4	OF1L	The eight LSB's of Fixed Offset OF[7:0].
5	GNTC1L	The eight LSB's of the first gain TC GNTC1[7:0].
6	OFTC1L	The eight LSB's of the first offset TC OFTC1[7:0].
7	TR1L PC5L	The eight LSB's of the first temperature point, T1[7:0]. The eight LSB's of Pressure Coefficient 5 PC5[7:0].
8	GNTC2L P5L	The eight LSB's of the second gain TC GNTC2[7:0]. The eight LSB's of Pressure Point 5 P5[7:0].
9	OFTC2L PC4L	The eight LSB's of the second offset TC OFTC2[7:0]. The eight LSB's of Pressure Coefficient 4 PC4[7:0].
10	TR2L P4L	The eight LSB's of the second temperature point T2[7:0]. The eight LSB's of Pressure Point 4 (or Signature) P4[7:0].
11	GNTC3L PC3L	The eight LSB's of the third gain TC GNTC3[7:0]. The eight LSB's of Pressure Coefficient 3 (or Signature) PC3 [8:0].



### Table 11. EEPROM Byte Definitions (continued)

Byte	Designation		Note	
12	OFTC3L or		The eight LSB's of the third offse	et TC OFTC3[7:0].
	P3L		The eight LSB's of Pressure Poin	t 2 (or Signature) P2[7:0].
13	TR3L or PC2L		The eight LSB's of the third temeight LSB's of Pressure Coefficie	
14	GNTC4L or P2L		The eight LSB's of the fourth gai eight LSB's of Pressure Point 2 P	
15	OFTC4L or PC1L		The eight LSB's of the fourth off eight LSB's of Pressure Coefficie	
16	PoffL		The eight LSB's of Pressure (out	put signal) Ordinate Poff[7:0].
	Upper Four Bits	Lower Four Bits	Upper four bits.	Lower four bits
17	GN1[9:8]	OF1[9:8]	Two MSB's of fixed gain GN[9:8].	Two MSB's of fixed offset OF[9:8]
18	GNTC1[11:8]	OFTC1[11:8]	Four MSB's of first gain TC GNTC1[11:8].	Four MSB's of the first offset TC OFTC1[11:8].
19	TR1[9:8] PC5[11:8]	GNTC2[11:8] P5[9:8]	Two MSB's, first temperature point T1[9:8] or Four MSB's, Pressure Coefficient 5 PC5[11:8].	Four MSB's, second gain TC GNTC2[11:8] or TC GNTC2[11:8] or Two MSB's Pressure Point 5 P5[9:8].
20	OFTC2[11:8] PC4[11:8]	TR2[9:8] P4[9:8]	Four MSB's second offset TC OFTC2[11:8] or Four MSB's Pressure Coefficient 4 PC4[11:8].	Two MSB's second temperature point T2[9:8] or Two MSB's Pressure Point 4 P4[9:8].
21	GNTC3[11:8] PC3[11:8]	OFTC3[11:8] P3[9:8]	Four MSB's third gain TC GNTC3[11:8] or Four MSB's Pressure Coefficient 3 PC3[11:8]).	Four MSB's third offset TC OFTC3[11:8] or Two MSB's Pressure Point 3 P3[9:8].
22	TR3[9:8] PC2[9:8]	GNTC4[11:8] P2[9:8]	Two MSB's third temperature point t3[9:8] or Four MSB's Pressure Coefficient 2 PC2[11:8].	Four MSB's fourth gain TC GNTC4[11:8] or Two MSB's Pressure Point 2 P2[9:8].
23	OFTC4[11:8] PC1[11:8]	Poff[9:8]	Four MSB's fourth offset TC ordinate OFTC4[11:8] or Four MSB's Pressure Coefficient 1 PC1[11:8].	Two MSB's Pressure Poff[9:8].



### Table 11. EEPROM Byte Definitions (continued)

Byte	Designation	Note	
24	PNB_TNB	Number of temperature and pressure gaps. See Tables 4, 5, and 6, and Figures 3 and 4.	
25	n_factor	Temperature filter coefficient, four LSB's. Four MSB's must all be zero.	
26	Not used	This byte is not used.	
27	ALARM low trigger Level1 IO2/IO1	Value below which ALARM will go on. Value of first level ([IO2, IO1]= 00-01). See Figures 5 & 7.	
28	ALARM low output Level2 IO2/IO1	Value of DIGMO during "ALARM low" condition. Value of second level ([IO2,IO1] = 01-10). See Figures 5 and 7	
29	ALARM high trigger Level3 IO2/IO1	Value above which ALARM will go on. Value of third level ([IO2,IO1]=10-11). See Figures 5 and 7.	
30	ALARM high out level	Value of DIGMO during "ALARM high" condition. See Figures 5 and 7.	
31	ALARM control byte	Three bits needed for choice of input for ALARM detection (TPO, IAO, GNO, VMO, IO1 or IO2).	
	IO1/IO2 control byte	Two bits needed for choice of input for LEVEL-steering (TPO, IAO, GNO or VMO).	
	Four LSB's are unused	The above bits are multiplexed according to the mode. If both CMO and VMO are active, then alarm is not active.	
32	ClkTC1	Value of Cadj at low temperature (Don't change; factory set).	
33	ClkTC2	Value of Cadj at mid temperature (Don't change; factory set).	
34	CIkTC3	Value of Cadj at high temperature Don't change; factory set).	
35	Ctemp1	First Cadj temperature point, eight MSB's of the 10 bit internal temperature value (set at factory; do not change).	
36	Ctemp2	Second Cadj temperature point, eight MSB's of the 10 bit internal temperature value (set at factory; do not change).	
37-38	Not used	These bytes are not used by the firmware and are available to the user.	
39	CLKgntp	Setting for temperature amplifier for clock temperature adjustment temperature reading (set at factory; do not change).	
40-41	Faultval	Value sent to output if checksum test fails is a 10 bit value.	
42-46	Not Used	These bytes are not used by the firmware and are available to the user.	
47	Checksum	EEPROM checksum; value needed to make all bytes add to OFFh. Must be set by user if checksum test is active.	



#### **Notes For Table 11**

- 1. Not all the temperature and pressure coefficients must be used. When a coefficient is unused, the eight LSB's and the four MSB's are replaced by 0.
- 2. The level steering and the alarm mode cannot be active simultaneously because the levels bytes are shared with the two modes.
- 3. If the alarm mode and the level steering are both active, the level steering mode is dominant. The firmware will run with the level steering mode, by default.
- 4. If the DIGMO mode (VMO and CMO both active) is active, the alarm will be automatically disabled by the firmware.
- 5. At PNB\_TNB address, the four MSB's correspond to the address of the last pressure point and the four LSB's to the address of the last temperature point.
- 6. In the alarm\_control variable, the selected input is stored on the three MSB's.
- 7. Pi and OFi are 10 bit values, right justified in 12 bits fields.

#### Table 12. Bit Definitions; Coarse Control, Byte 2

Bit	Symbol	Function	
7	IINV	Invert signal sign.	
6	GNTP1	Gain & offset of temperature amplifier.	
5	GNTP0	GNTP = 0 to 3.	
4	CSOF 1	Coarse offset of signal amplifier.	
3	CSOF 0	CSOF = 0 to 3.	
2	CSGN2	Coarse gain of signal amplifier.	
1	CSGN1	CSGN = 0 to 7. If $CSGN > 3$ output range = 0 to 10V.	
0	CSGN0	CSGN <= 3, output range = 0 t 5V.	

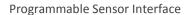
#### **Table 13. RAM Byte Definitions**

Byte	Functions	Remarks
0	MODE byte	See Table 9.
1	GN1L	Fixed gain number (8LSB).
2	OF1L	Fixed offset number (8LSB).
3	GNTC1L	First gain TC (8LSB).
4	OFTC1L	First offset TC (8LSB).
5	TR1L PC5L	First temperature point. Pressure Coefficient 5 (8LSB).
6	GNTC2L P5L	Second gain TC. Pressure point 5 (8LSB).
7	OFTC2L PC4L	Second offset TC. Pressure coefficient 4 (8LSB).
8	TR2L P4L	Second temperature point. Pressure Point 4 (or Signature) (8LSB).
9	GNTC3L PC3L	Third gain TC. Pressure Coefficient 3 (or Signature) (8LSB).
10	OFTC3L P3L	Third offset TC. Pressure Point 2 (or Signature) (8LSB).





Byte	Functions		Remarks	
11	TR3L		Third temperature point.	
111	INSL		mira temperature point.	
	PC2L		Pressure Coefficient 2 (8LSB).	
12	GNTC4L		Fourth gain TC.	
	P2L		Pressure Point 1 (8LSB).	
13	OFTC4L		Fourth offset TC.	
	PC1L		Pressure Coefficient 1 (8LSB).	
14	DIGMOP1L		Fixed pressure (8LSB).	
15	GN1[9:8]	OF1[9:8]	Two MSB's of fixed gain GN[9:8].	Two MSB's of fixed offset OF[9:8].
16	GNTC1	OFTC1	Four MSB's of first gain TC	Four MSB's of the first
	[11:8]	[11:8]	GNTC1[11:8].	offset TC OFTC1[11:8]
17	TR1[9:8]	GNTC2	Two MSB's, first temperature	Four MSB's, second gain
		[11:8]	point T1[9:8] or	TC GNTC2[11:8] or
	PC5[11:8]	P5[9:8]	Four MSB's Pressure	Two MSB's, Pressure
10	OFTC2[44.0]	TD2[0.0]	Coefficient 5 PC5[11:8].	Point 5 P5[9:8]
18	OFTC2[11:8]	TR2[9:8]	Four MSB's, second offset TC OFTC2[11:8] or	Two MSB's, second temp.
	PC4[11:8]	P4[9:8]	OFICZ[11.8] 01	point T2[9:8] or
	PC4[11.0]	P4[3.0]	Four MSB's, Pressure	Two MSB's, Pressure
			Coefficient 4 PC4[11:8].	Point 4 P4[9:8].
19	GNTC3[11:8]	OFTC3	Four MSB's, Third Gain TC	Four MSB's Third Offset
	[11:8]		GNTC3[11:8] or	TC OFTC3[11:8] or
	DC2[44.0]	0.010	Four MSB's, Pressure	Two MSB's Pressure
20	PC3[11:8]	P3[9:8]	Coefficient 3 PC3[11:8]).	Point 3 P3[9:8]
20	TR3[9:8]	GNTC4	Two MSB's, third temperature point t3[9:8] or	Four MSB's, Fourth Gain TC GNTC4[11:8] or
	[11:8]		, panie (3,13,13)	. 5 5.1. 5 1[11.0] 6
			Four MSB's, Pressure	Two MSB's, Pressure
	PC2[9:8]	P2[9:8]	Coefficient 2 PC2[11:8].	Point 2 P2[9:8].
21	OFTC4[11:8]	P1[9:8]	Four MSB's Fourth Offset TC	Two MSB's Pressure
			OFTC4[11:8] or	Point 1 P1[9:8].
	DC4[44 0]		Farm MCDIa Duare	
	PC1[11:8]		Four MSB's Pressure	
22	PNB TNB		Coefficient 1 PC1[11:8]. Same as EEPROM.	
23	N_Factor		Temperature filter coefficient —	4 LSB's, 4 MSB = 0
24	Not Used			•
25-26	GN Offset Ordinate of the current gap.			
27-28	<b>0</b> 1			
29	Taddress		4 bits for the max. temperature	
			bits for the min. temperature ad	dress of the current gap.





ALARM control byte 101/102 con	Byte	Functions	Remarks
needed for choice of input for LEVEL-steering (TPO, IAO, GNO or VMO). These bits are multiplexed according the mode. Note: if both CMO and VMO are active, then alarm is not active.  31 ALARM low trigger level Value below which ALARM will go on.    IO1/IO2 level 1	30	ALARM control byte	Three bits needed for choice of input for ALARM
GNO or VMO). These bits are multiplexed according the mode. Note: if both CMO and VMO are active, then alarm is not active.  31 ALARM low trigger level Value below which ALARM will go on.    IO1/IO2 level 1 Value of first level ([IO2,IO1]=00-01).   32 ALARM low output level Value of DIGMO during "ALARM low" condition.   IO1/IO2 level 2 Value of second level ([IO2,IO1]=01-10).   33 ALARM high trigger level Value above which ALARM will go on.   Value of third level ([IO2,IO1] = 10-11).   IO1/IO2 level 3 Value of DIGMO during "ALARM high" condition. level (IO2,IO1] = 10-11).   35-36 A_16		IO1/IO2 control byte	detection (TPO, IAO, GNO, VMO, IO1 or IO2). Two bits
VMO). These bits are multiplexed according the mode. Note: if both CMO and VMO are active, then alarm is not active.  31 ALARM low trigger level Value below which ALARM will go on.    IO1/IO2 level 1 Value of first level ([IO2,IO1]=00-01).   Value of DIGMO during "ALARM low" condition.   IO1/IO2 level 2 Value of second level ([IO2,IO1]=01-10).   Value above which ALARM will go on.   Value of third level ([IO2,IO1] = 10-11).   IO1/IO2 level 3 Value of DIGMO during "ALARM high" condition.   Io1/IO2 level 3 Value of DIGMO during "ALARM high" condition.   Value of third level ([IO2,IO1]=0-10).   Value of DIGMO during "ALARM high" condition.			needed for choice of input for LEVEL-steering (TPO, IAO,
if both CMO and VMO are active, then alarm is not active.  ALARM low trigger level Value below which ALARM will go on.  Value of first level ([IO2.IO1]=00-01).  Value of DIGMO during "ALARM low" condition.  Value of second level ([IO2,IO1]=01-10).  Value of second level ([IO2,IO1]=01-10).  Value of third level ([IO2,IO1]=01-10).  Value of DIGMO during "ALARM will go on.  Value of DIGMO during "ALARM high" condition.  Value of DIGMO during "ALARM high" condition.  Ievel  35-36 A_16 16 bits A Register.  37-38 B_16 16 bits B Register.  39-42 RESULT_32 32 bits result (for 16 bit multiplication).  Measured temperature, internal or external, and temporary variable 1.  45 Tempo2 Temporary variable 2.  46-47 Signal_In Digitized signal value, analog and digital mode  48 Coms_backup Address saved when command is send.  49 P3_copy Port 3 setting copy.  50 Adsav1 Address saved at interrupt.  51-52 Aaccsav A-Accumulators saved at interrupt.  51-52 Aaccsav B-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC gain DAC offset DAC offset (OF).  Filtered temperature. This is a 10 bit number that is left			GNO or
ALARM low trigger level   Value below which ALARM will go on.			VMO). These bits are multiplexed according the mode. Note:
IO1/IO2 level 1   Value of first level ([IO2.IO1]=00-01).     32   ALARM low output level   Value of DIGMO during "ALARM low" condition.     IO1/IO2 level 2   Value of second level ([IO2,IO1]=01-10).     33   ALARM high trigger level   Value above which ALARM will go on.     IO1/IO2 level 3   Value of third level ([IO2,IO1] = 10-11).     34   ALARM high output level   Value of DIGMO during "ALARM high" condition.     35-36   A_16   16 bits A Register.     37-38   B_16   16 bits B Register.     39-42   RESULT_32   32 bits result (for 16 bit multiplication).     43-44   Tempo1   Measured temperature, internal or external, and temporary variable 1.     45   Tempo2   Temporary variable 2.     46-47   Signal_In   Digitized signal value, analog and digital mode     48   Coms_backup   Address saved when command is send.     49   P3_copy   Port 3 setting copy.     50   Adsav1   Address saved at interrupt.     51-52   Aaccsav   A-Accumulators saved at interrupt.     53   Baccsav   B-Accumulators saved at interrupt.     54-55   DAC_gain   DAC offset (OF).     58-59   Temp_f   Filtered temperature. This is a 10 bit number that is left			if both CMO and VMO are active, then alarm is not active.
32   ALARM low output level   Value of DIGMO during "ALARM low" condition.	31	ALARM low trigger level	Value below which ALARM will go on.
IO1/IO2 level 2   Value of second level ([IO2,IO1]=01-10).     33		IO1/IO2 level 1	Value of first level ([IO2,IO1]=00-01).
ALARM high trigger level   Value above which ALARM will go on.	32	ALARM low output level	Value of DIGMO during "ALARM low" condition.
ALARM high trigger level   Value above which ALARM will go on.			
level   IO1/IO2 level 3		IO1/IO2 level 2	Value of second level ([IO2,IO1]=01-10).
Value of third level ([IO2,IO1] = 10-11).  34 ALARM high output level  35-36 A_16  37-38 B_16  39-42 RESULT_32  43-44 Tempo1  45 Tempo2  46-47 Signal_In  Digitized signal value, analog and digital mode  48 Coms_backup  Address saved when command is send.  49 P3_copy  Port 3 setting copy.  50 Adsav1  Address saved at interrupt.  51-52 Aaccsav  B-Accumulators saved at interrupt.  54-55 DAC_gain  DAC gain (GN).  Value of third level ([IO2,IO1] = 10-11).  Value of third level ([IO2,IO1] = 10-11.  Value of DIGMO  Measured temperature, internal or external, and temporary variable 1.  Value of the plant in the plant i	33	ALARM high trigger	Value above which ALARM will go on.
IO1/IO2 level 3		level	
34 ALARM high output level  35-36 A_16  37-38 B_16  39-42 RESULT_32  32 bits result (for 16 bit multiplication).  43-44 Tempo1  45 Tempo2  46-47 Signal_In  48 Coms_backup  48 Coms_backup  49 P3_copy  50 Adsav1  51-52 Aaccsav  54-55 DAC_gain  54-55 DAC_gain  55-57 DAC_offset  51-52 Aaccost  54-55 DAC_offset  54-65 Tempo1  Value of DIGMO during "ALARM high" condition.  16 bits A Register.  16 bits A Register.  18 bits A Register.  19 bits a libit multiplication).  Measured temperature, internal or external, and temporary variable 2.  Digitized signal value, analog and digital mode  48 Coms_backup  Address saved when command is send.  49 P3_copy  Port 3 setting copy.  50 Adsav1  Address saved at interrupt.  51-52 Aaccsav  A-Accumulators saved at interrupt.  53 Baccsav  B-Accumulators saved at interrupt.  54-55 DAC_gain  DAC gain (GN).  56-57 DAC_offset  DAC offset (OF).  Filtered temperature. This is a 10 bit number that is left			Value of third level ([IO2,IO1] = 10-11).
level  35-36 A_16  37-38 B_16  39-42 RESULT_32  32 bits result (for 16 bit multiplication).  43-44 Tempo1  Measured temperature, internal or external, and temporary variable 1.  45 Tempo2  Temporary variable 2.  46-47 Signal_In  Digitized signal value, analog and digital mode  48 Coms_backup  Address saved when command is send.  49 P3_copy  Port 3 setting copy.  50 Adsav1  Address saved at interrupt.  51-52 Aaccsav  A-Accumulators saved at interrupt.  53 Baccsav  B-Accumulators saved at interrupt.  54-55 DAC_gain  DAC gain (GN).  56-57 DAC_offset  DAC offset  DAC offset (OF).  Filtered temperature. This is a 10 bit number that is left		IO1/IO2 level 3	
35-36A_1616 bits A Register.37-38B_1616 bits B Register.39-42RESULT_3232 bits result (for 16 bit multiplication).43-44Tempo1Measured temperature, internal or external, and temporary variable 1.45Tempo2Temporary variable 2.46-47Signal_InDigitized signal value, analog and digital mode48Coms_backupAddress saved when command is send.49P3_copyPort 3 setting copy.50Adsav1Address saved at interrupt.51-52AaccsavA-Accumulators saved at interrupt.53BaccsavB-Accumulators saved at interrupt.54-55DAC_gainDAC gain (GN).56-57DAC_offsetDAC offset (OF).58-59Temp_fFiltered temperature. This is a 10 bit number that is left	34	ALARM high output	Value of DIGMO during "ALARM high" condition.
37-38 B_16 16 bits B Register.  39-42 RESULT_32 32 bits result (for 16 bit multiplication).  43-44 Tempo1 Measured temperature, internal or external, and temporary variable 1.  45 Tempo2 Temporary variable 2.  46-47 Signal_In Digitized signal value, analog and digital mode  48 Coms_backup Address saved when command is send.  49 P3_copy Port 3 setting copy.  50 Adsav1 Address saved at interrupt.  51-52 Aaccsav A-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC_gain DAC gain (GN).  56-57 DAC_offset DAC offset (OF).  58-59 Temp_f Filtered temperature. This is a 10 bit number that is left		level	
39-42 RESULT_32 32 bits result (for 16 bit multiplication).  43-44 Tempo1 Measured temperature, internal or external, and temporary variable 1.  45 Tempo2 Temporary variable 2.  46-47 Signal_In Digitized signal value, analog and digital mode  48 Coms_backup Address saved when command is send.  49 P3_copy Port 3 setting copy.  50 Adsav1 Address saved at interrupt.  51-52 Aaccsav A-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC_gain DAC gain (GN).  56-57 DAC_offset DAC offset (OF).  58-59 Temp_f Filtered temperature. This is a 10 bit number that is left	35-36	A_16	16 bits A Register.
43-44 Tempo1 Measured temperature, internal or external, and temporary variable 1.  45 Tempo2 Temporary variable 2.  46-47 Signal_In Digitized signal value, analog and digital mode  48 Coms_backup Address saved when command is send.  49 P3_copy Port 3 setting copy.  50 Adsav1 Address saved at interrupt.  51-52 Aaccsav A-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC_gain DAC gain (GN).  56-57 DAC_offset DAC offset (OF).  58-59 Temp_f Filtered temperature. This is a 10 bit number that is left	37-38	B_16	16 bits B Register.
temporary variable 1.  45 Tempo2 Temporary variable 2.  46-47 Signal_In Digitized signal value, analog and digital mode  48 Coms_backup Address saved when command is send.  49 P3_copy Port 3 setting copy.  50 Adsav1 Address saved at interrupt.  51-52 Aaccsav A-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC_gain DAC gain (GN).  56-57 DAC_offset DAC offset (OF).  58-59 Temp_f Filtered temperature. This is a 10 bit number that is left	39-42	RESULT_32	32 bits result (for 16 bit multiplication).
45 Tempo2 Temporary variable 2.  46-47 Signal_In Digitized signal value, analog and digital mode  48 Coms_backup Address saved when command is send.  49 P3_copy Port 3 setting copy.  50 Adsav1 Address saved at interrupt.  51-52 Aaccsav A-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC_gain DAC gain (GN).  56-57 DAC_offset DAC offset (OF).  58-59 Temp_f Filtered temperature. This is a 10 bit number that is left	43-44	Tempo1	Measured temperature, internal or external, and
46-47 Signal_In Digitized signal value, analog and digital mode  48 Coms_backup Address saved when command is send.  49 P3_copy Port 3 setting copy.  50 Adsav1 Address saved at interrupt.  51-52 Aaccsav A-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC_gain DAC gain (GN).  56-57 DAC_offset DAC offset (OF).  58-59 Temp_f Filtered temperature. This is a 10 bit number that is left			temporary variable 1.
48 Coms_backup Address saved when command is send.  49 P3_copy Port 3 setting copy.  50 Adsav1 Address saved at interrupt.  51-52 Aaccsav A-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC_gain DAC gain (GN).  56-57 DAC_offset DAC offset (OF).  58-59 Temp_f Filtered temperature. This is a 10 bit number that is left	45	Tempo2	Temporary variable 2.
49 P3_copy Port 3 setting copy. 50 Adsav1 Address saved at interrupt. 51-52 Aaccsav A-Accumulators saved at interrupt. 53 Baccsav B-Accumulators saved at interrupt. 54-55 DAC_gain DAC gain (GN). 56-57 DAC_offset DAC offset (OF). 58-59 Temp_f Filtered temperature. This is a 10 bit number that is left	46-47	Signal_In	Digitized signal value, analog and digital mode
50 Adsav1 Address saved at interrupt.  51-52 Aaccsav A-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC_gain DAC gain (GN).  56-57 DAC_offset DAC offset (OF).  58-59 Temp_f Filtered temperature. This is a 10 bit number that is left	48	Coms_backup	Address saved when command is send.
51-52 Aaccsav A-Accumulators saved at interrupt.  53 Baccsav B-Accumulators saved at interrupt.  54-55 DAC_gain DAC gain (GN).  56-57 DAC_offset DAC offset (OF).  58-59 Temp_f Filtered temperature. This is a 10 bit number that is left	49	P3_copy	Port 3 setting copy.
53BaccsavB-Accumulators saved at interrupt.54-55DAC_gainDAC gain (GN).56-57DAC_offsetDAC offset (OF).58-59Temp_fFiltered temperature. This is a 10 bit number that is left	50	Adsav1	Address saved at interrupt.
54-55DAC_gainDAC gain (GN).56-57DAC_offsetDAC offset (OF).58-59Temp_fFiltered temperature. This is a 10 bit number that is left		Aaccsav	
56-57 DAC_offset DAC offset (OF). 58-59 Temp_f Filtered temperature. This is a 10 bit number that is left			
58-59 Temp_f Filtered temperature. This is a 10 bit number that is left			
· — ·			
	58-59	remp_r	·
60-61 Signal_Out Digitized linearity corrected signal value. Digital mode only.	60-61	Signal Out	,
62-63 Adsav2 Address saved when call.			

**Note:** Because of space considerations, the measured temperature can't be kept in the RAM at all times. If the measured temperature is to be available, the temperature filter variable, N\_Factor, must be set to 6.

Programmable Sensor Interface



### **Prototyping**

Melexis offers an MLX90314 evaluation kit which contains an evaluation circuit board, serial interface cable, and software diskette. The circuit board provides the necessary circuitry for all three applications circuits shown on the next page. Also included in the circuit board is level shifting and glue logic necessary for RS-232 communications.

The board has a socket with a single MLX90314 installed, and direct access to the pins of the IC. The user can easily attach bridge sensor to the board for in-system evaluation. The serial interface cable connects the evaluation board directly to a PC's serial port for in-system calibration.

The software runs in the familiar Windows platform and allows for programming and evaluation of all compensation parameters within the EEPROM.

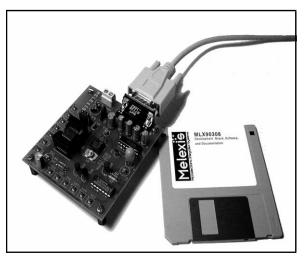
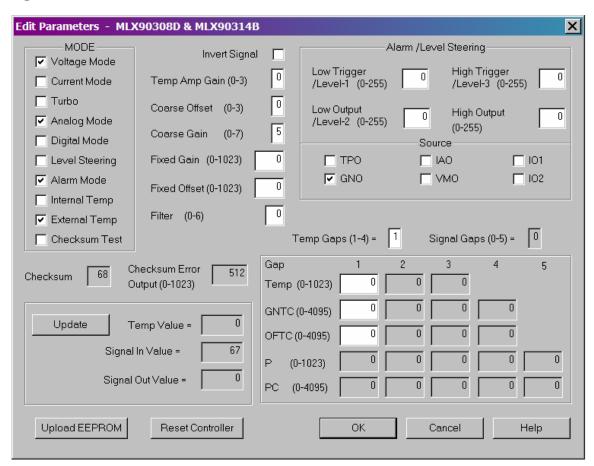


Figure 8. MLX90314 Evaluation Kit with MLX Software





### 13. Typical 90314 Applications

### Figure 9a. Absolute Voltage Mode

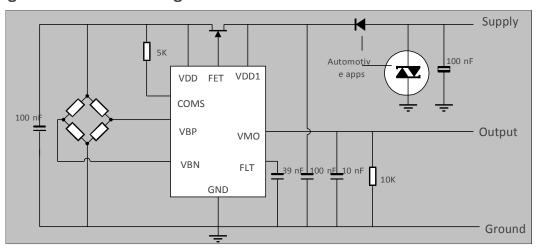
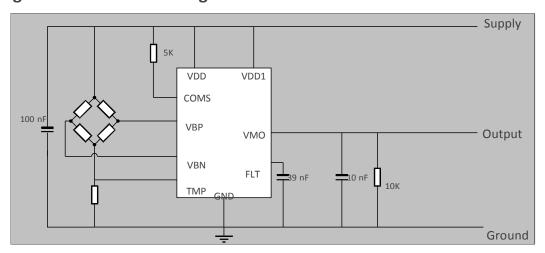


Figure 9b. Ratiometric Voltage Mode

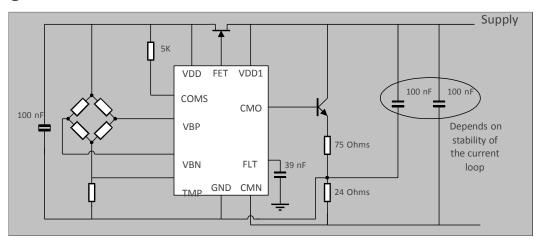


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Programmable Sensor Interface



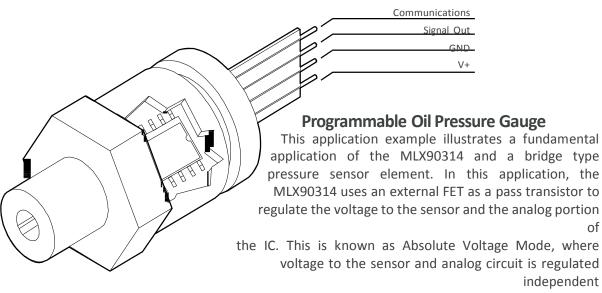
#### Figure 9c. Current Mode





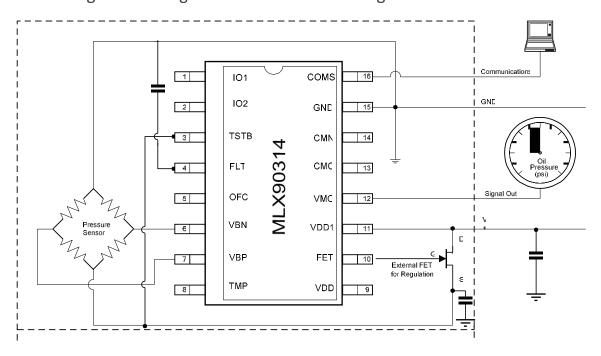
#### Figure 10. Application Example

Figure 10a. Programmable Oil Pressure Gauge



of the supply voltage. The MLX90314 can be operated in Ratiometric Voltage Mode, in which the output (VMO) is tied to an A/D converter sharing the same supply and ground reference. A third wiring option is Current Mode, which allows the user a 4 to 20 milliampere current range to use as a 2-wire analog sensor.

Figure 10b. Programmable Oil Pressure Gauge Electrical Connections





#### Figure 11. Error Compensation

# Figure 11a. Raw Sensor Output (measured between VPB and VBN)

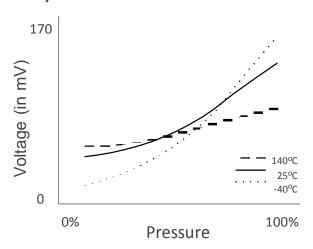
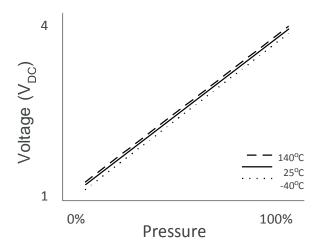


Figure 11b. Conditioned Sensor Output



Figures 11a and 11b above illustrate the performance of an unconditioned sensor output and a conditioned sensor output versus stimulus (pressure) and temperature. It can be seen that Figure 11a has a range of only 170 mV (maximum range with a 5V supply) and has a non-linear response over a 0-100 psi range. The sensitivity of the unconditioned output will also drift over temperature, as illustrated by the three slopes. The MLX90314 corrects these errors and amplifies the output to a more usable voltage range as shown in Figure 11b.

Programmable Sensor Interface

# Melexis INSPIRED ENGINEERING

#### **Table 14. Glossary of Terms**

A/D analog to digital conversion ADC analog to digital converter

ASCII American Standard Code for Information

Interchange

ASIC application specific integrated circuit

CM current mode

CMN current mode negative (supply connection) CMO current mode output

COMS communication, serial

CR carriage return CSGN coarse gain CSOF coarse offset

CV current / voltage mode select bit DAC digital to analog converter DACFnew filtered DAC value, new DACFold filtered DAC value, old DARDIS

DAC resistor disable

dB decibel

DOGMO digital mode

EEPROM electrically erasable programmable

read only memory EOC end of conversion flag bit ESD electrostatic discharge ETMI timer

interrupt enable

ETPI enable temperature interrupt

FET field effect transistor

FG fixed gain FLT filter pin

GNO gain and offset adjusted digitized signal

GNOF gain, offset

GNTP temperature gain / offset coarse adjustment

HS hardware / software limit

I/O input / output

IFIX fixed current output value

IINV input signal invert command bit

ILIM current limit

kHz kilohertz, 1000 Hz

LSB least significant bit

mA milliamperes, 0.001 amps

MODSEL mode select

ms millisecond, 0.001 second

MSB most significant bit

MUX multiplexer

mV millivolts, 0.001 Volts nF nanofarads, 1 X 10<sup>-9</sup> farads

OFC offset control

PC personal computer, IBM clone pF picofarad, 1 X 10<sup>-12</sup>

arads

PLL phase locked loop

POR power on reset

RAM random access memory

RISC reduced instruction set computer

ROM read only memory

RS-232 industry std. serial communications protocol

RX receive

SAR successive approximation register

STC start A/D

conversion Tdiff

temperature difference

Text temperature,

external TMI timer

Interrupt

TMP temperature

signal TPI temperature

interrupt Tref

temperature reference

TSTB test mode pin

TX transmit

UART universal asynchronous receiver / transmitter

VBN bridge, positive, input VBP bridge, negative, input VDD supply voltage VM voltage mode

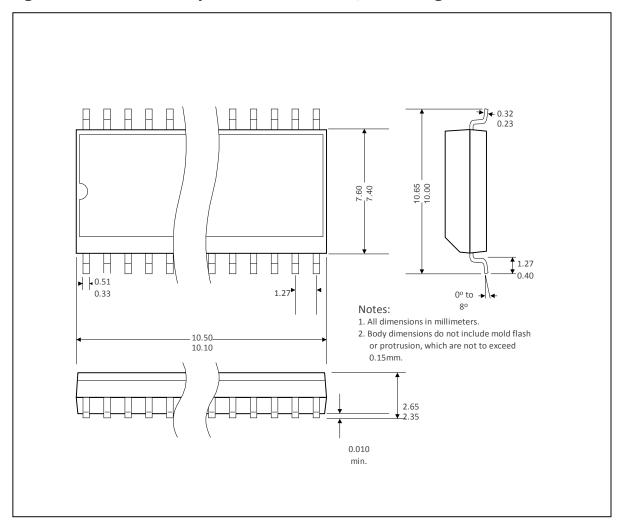
VMGN voltage mode gain VMO voltage

mode output WCB warn / cold boot WDC

watch dog counter



Figure 12. MLX90314 Physical Characteristics, DF Package





# 14. Standard information regarding manufacturability of Melexis products with different soldering processes

Our products are classified and qualified regarding soldering technology, solderability and moisture sensitivity level according to following test methods:

#### **Reflow Soldering SMD's (Surface Mount Devices)**

- IPC/JEDEC J-STD-020
   Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices (classification reflow profiles according to table 5-2)
- EIA/JEDEC JESD22-A113
   Preconditioning of Nonhermetic Surface Mount Devices Prior to Reliability Testing (reflow profiles according to table 2)

#### Wave Soldering SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

- EN60749-20
  - Resistance of plastic- encapsulated SMD's to combined effect of moisture and soldering heat
- EIA/JEDEC JESD22-B106 and EN60749-15
   Resistance to soldering temperature for through-hole mounted devices

#### Iron Soldering THD's (Through Hole Devices)

EN60749-15
 Resistance to soldering temperature for through-hole mounted devices

#### Solderability SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

 EIA/JEDEC JESD22-B102 and EN60749-21 Solderability

For all soldering technologies deviating from above mentioned standard conditions (regarding peak temperature, temperature gradient, temperature profile etc) additional classification and qualification tests have to be agreed upon with Melexis.

The application of Wave Soldering for SMD's is allowed only after consulting Melexis regarding assurance of adhesive strength between device and board.

Melexis is contributing to global environmental conservation by promoting **lead free** solutions. For more information on qualifications of **RoHS** compliant products (RoHS = European directive on the Restriction Of the use of certain Hazardous Substances) please visit the quality page on our website: <a href="http://www.melexis.com/quality.aspx">http://www.melexis.com/quality.aspx</a>

39010903214 Page 32 of 33

Programmable Sensor Interface



#### 15. Contact

For the latest version of this document, go to our website at www.melexis.com.

For additional information, please contact our Direct Sales team and get help for your specific needs:

Europe, Africa	Telephone: +32 13 67 04 95	
	Email: sales_europe@melexis.com	
Americas	Telephone: +1 603 223 2362	
	Email : sales_usa@melexis.com	
Asia	Email : sales_asia@melexis.com	

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